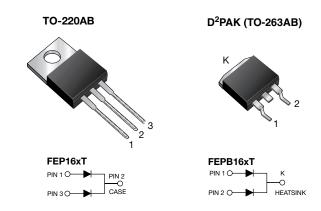
HALOGEN

FREE



Vishay General Semiconductor

Dual Common Cathode Ultrafast Plastic Rectifier



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 8.0 A					
V_{RRM}	50 V to 600 V					
I _{FSM}	200 A, 125 A					
t _{rr}	35 ns, 50 ns					
V _F	0.95 V, 1.30 V, 1.50 V					
T _J max.	150 °C					
Package	TO-220AB, D ² PAK (TO-263AB)					
Circuit configurations	Common cathode					

FEATURES

- Power pack
- · Glass passivated pellet chip junction
- · Ultrafast recovery time
- · Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 for TO-220AB package
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHM3 for D²PAK (TO-263AB package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - RoHS-compliant, halogen-free, commercial

grade

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101

qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test,

HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.



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MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	FEP16AT	FEP16BT	FEP16CT	FEP16DT FEPB16DT	FEP16FT	FEP16GT FEPB16GT	FEP16HT	FEP16JT FEPB16JT	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	500	600	٧
Maximum average forward rectified current at T _C = 100 °C	I _{F(AV)}		16							А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	200 125							А	
Operating storage and temperature range	T _J , T _{STG}		-55 to +150						°C	

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)												
PARAMETER	TEST CONDITIONS	SYMBOL	FEP16AT	FEP16BT	FEP16CT	FEP16DT FEPB16DT	FEP16FT	FEP16GT FEPB16GT	FEP16HT	FEP16JT FEPB16JT	UNIT	
Maximum instantaneous forward voltage per diode	8.0 A	V _F ⁽¹⁾	0.95 1.30 1.50						V			
Maximum DC reverse current	T _C = 25 °C	10										
per diode at rated DC blocking voltage	T _C = 100 °C	I _R	500							μΑ		
Maximum reverse recovery time per diode	$I_F = 0.5 A,$ $I_R = 1.0 A,$ $I_{rr} = 0.25 A$	t _{rr}	35 50						ns			
Typical junction capacitance per diode	4.0 V, 1 MHz	СЈ	85 60						pF			

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER SYMBOL FEP FEPF FEPB UNI								
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	2.2	3.1	2.2	°C/W			

ORDERING INFORMATION (Example)								
PACKAGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY MODE								
TO-220AB	FEP16JT-E3/45	1.85	45	50/tube	Tube			
D ² PAK (TO-263AB)	FEPB16JT-M3/I	1.35	I	800/reel	Tape and reel			
D ² PAK (TO-263AB)	FEPB16JTHM3/I (1)	1.35	I	800/reel	Tape and reel			

Note

⁽¹⁾ AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

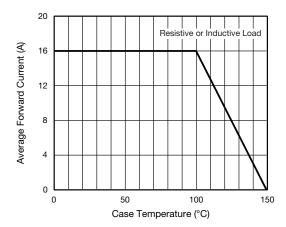


Fig. 1 - Forward Current Derating Curve

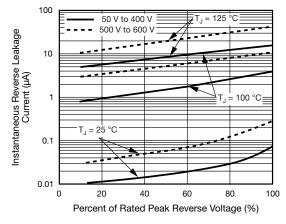


Fig. 4 - Typical Reverse Characteristics Per Diode

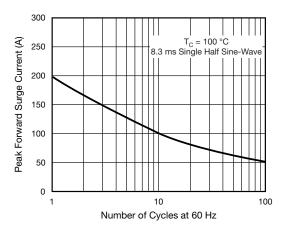


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

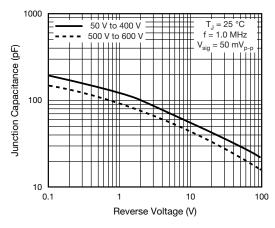


Fig. 5 - Typical Junction Capacitance Per Diode

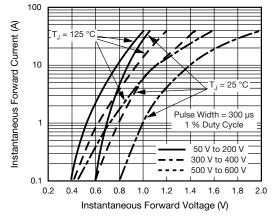
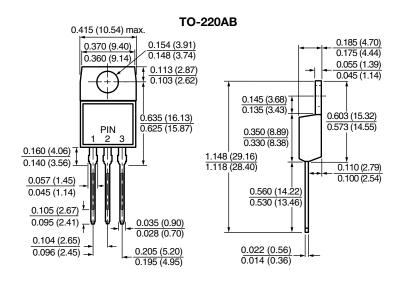


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



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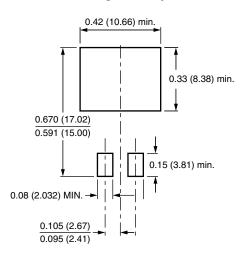
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)

0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout





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